

# 2SJ680

## Switching Applications

Chopper Regulator, DC/DC Converter and Motor Drive Applications

- Low drain-source ON-resistance:  $R_{DS(ON)} = 1.6 \Omega$  (typ.)
- High forward transfer admittance:  $|Y_{fs}| = 2.0 \text{ S}$  (typ.)
- Low leakage current:  $I_{DSS} = -100 \mu\text{A}$  (max) ( $V_{DS} = -200 \text{ V}$ )
- Enhancement model:  $V_{th} = -1.5 \sim -3.5 \text{ V}$  ( $V_{DS} = -10 \text{ V}$ ,  $I_D = -1 \text{ mA}$ )

## Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit
Drain-source voltage		$V_{DSS}$	-200	V
Drain-gate voltage ( $R_{GS} = 20 \text{ k}\Omega$ )		$V_{DGR}$	-200	V
Gate-source voltage		$V_{GSS}$	$\pm 20$	V
Drain current	DC (Note 1)	$I_D$	-2.5	A
	Pulse (Note 1)	$I_{DP}$	-10	
Drain power dissipation ( $T_c = 25^\circ\text{C}$ )		$P_D$	20	W
Single pulse avalanche energy (Note 2)		$E_{AS}$	97.5	mJ
Avalanche current		$I_{AR}$	-2.5	A
Repetitive avalanche energy (Note 3)		$E_{AR}$	2.0	mJ
Channel temperature		$T_{ch}$	150	$^\circ\text{C}$
Storage temperature range		$T_{stg}$	-55~150	$^\circ\text{C}$

## Thermal Characteristics

Characteristic	Symbol	Max	Unit
Thermal resistance, channel to case	$R_{th(ch-c)}$	6.25	$^\circ\text{C/W}$
Thermal resistance, channel to ambient	$R_{th(ch-a)}$	125	$^\circ\text{C/W}$

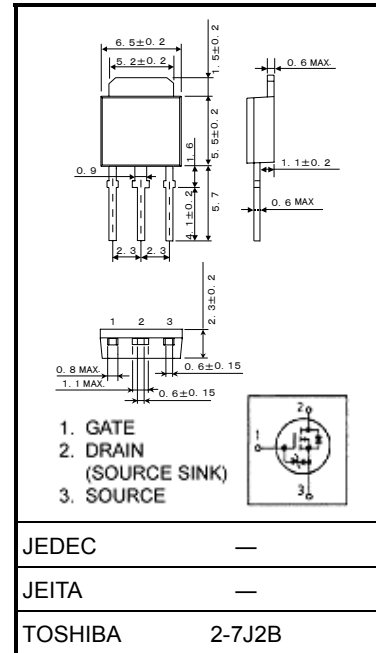
Note 1: Ensure that the channel temperature does not exceed  $150^\circ\text{C}$ .

Note 2:  $V_{DD} = -50 \text{ V}$ ,  $T_{ch} = 25^\circ\text{C}$  (initial),  $L = -25.2 \text{ mH}$ ,  $I_{AR} = -2.5 \text{ A}$ ,  $R_G = 25 \Omega$

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device. Handle with care.

Unit: mm



Weight: 0.36 g (typ.)

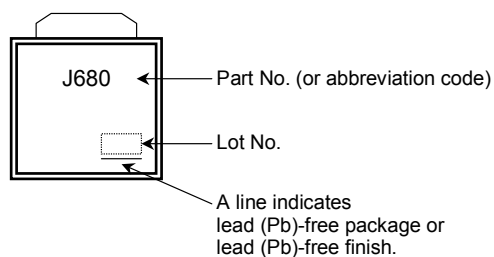
## Electrical Characteristics (Ta = 25°C)

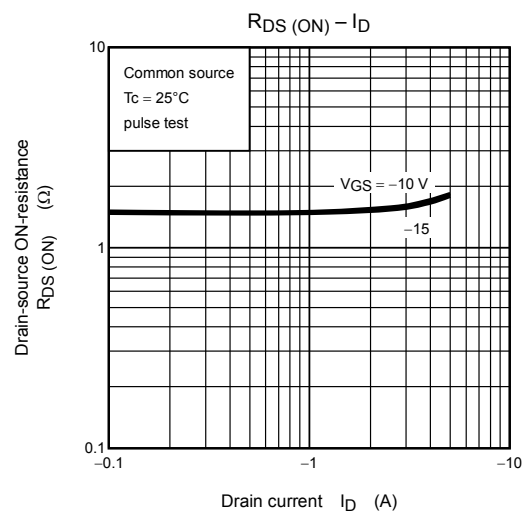
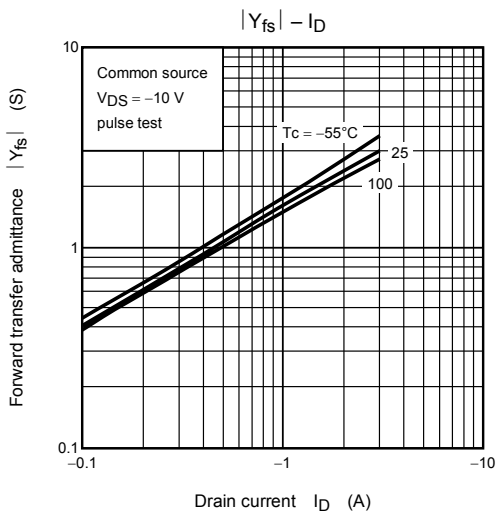
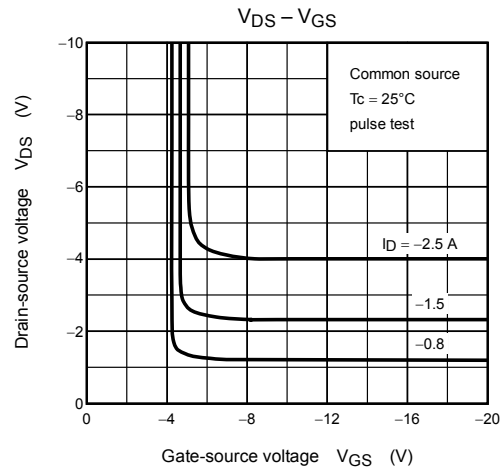
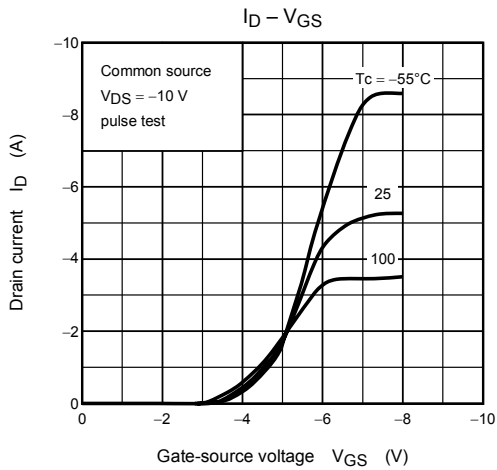
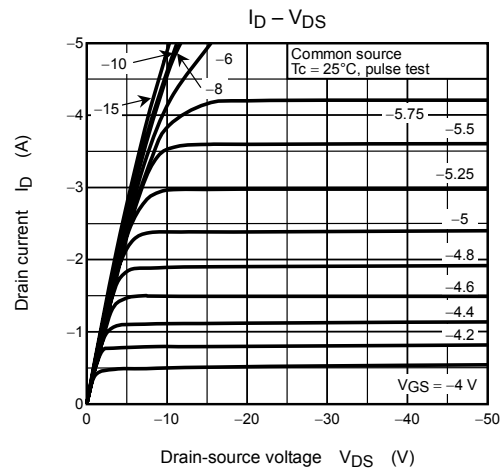
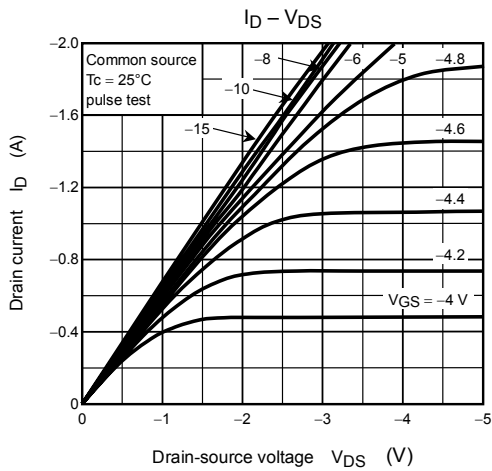
Characteristic		Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current		$I_{GSS}$	$V_{GS} = \pm 16\text{ V}, V_{DS} = 0\text{ V}$	—	—	$\pm 10$	$\mu\text{A}$
Drain cutoff current		$I_{DSS}$	$V_{DS} = -200\text{ V}, V_{GS} = 0\text{ V}$	—	—	-100	$\mu\text{A}$
Drain-source breakdown voltage		$V_{(BR)DSS}$	$I_D = -10\text{ mA}, V_{GS} = 0\text{ V}$	-200	—	—	V
Gate threshold voltage		$V_{th}$	$V_{DS} = -10\text{ V}, I_D = -1\text{ mA}$	-1.5	—	-3.5	V
Drain-source ON-resistance		$R_{DS(ON)}$	$V_{GS} = -10\text{ V}, I_D = -1.5\text{ A}$	—	1.6	2.0	$\Omega$
Forward transfer admittance		$ Y_{fs} $	$V_{DS} = -10\text{ V}, I_D = -1.5\text{ A}$	1.0	2.0	—	S
Input capacitance		$C_{iss}$	$V_{DS} = -10\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$	—	410	—	pF
Reverse transfer capacitance		$C_{rss}$		—	40	—	
Output capacitance		$C_{oss}$		—	145	—	
Switching time	Rise time	$t_r$		—	20	—	ns
	Turn-on time	$t_{on}$		—	45	—	
	Fall time	$t_f$		—	15	—	
	Turn-off time	$t_{off}$		—	85	—	
Total gate charge (gate-source plus gate-drain)		$Q_g$	$V_{DD} \approx -160\text{ V}, V_{GS} = -10\text{ V}, I_D = -2.5\text{ A}$	—	10	—	nC
Gate-source charge		$Q_{gs}$		—	6	—	
Gate-drain ("Miller") charge		$Q_{gd}$		—	4	—	

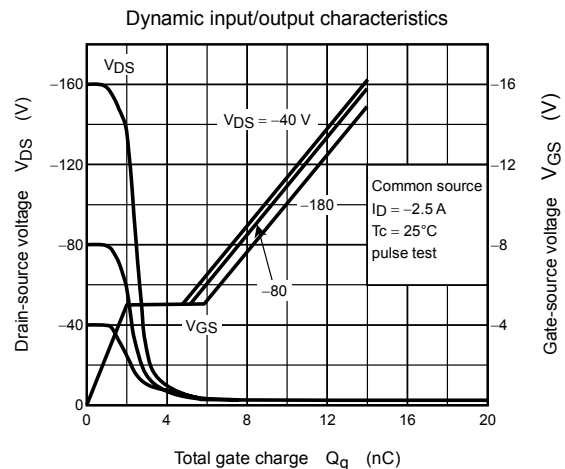
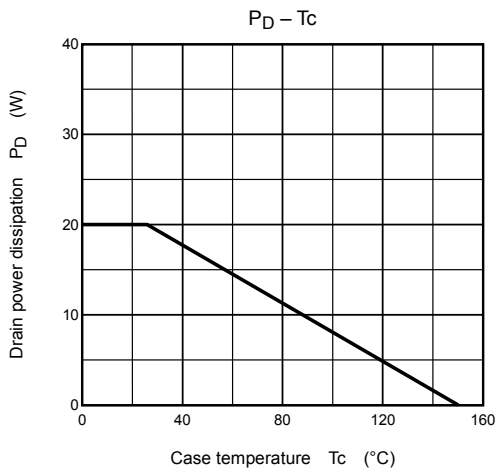
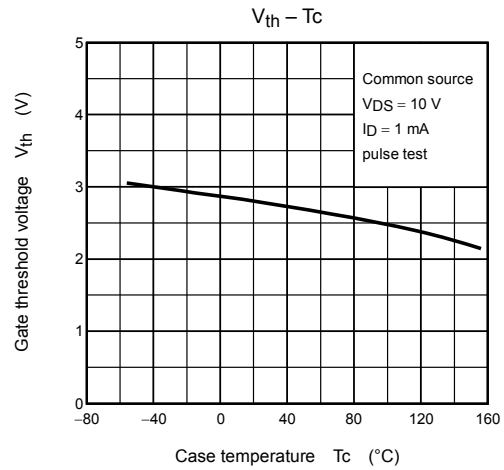
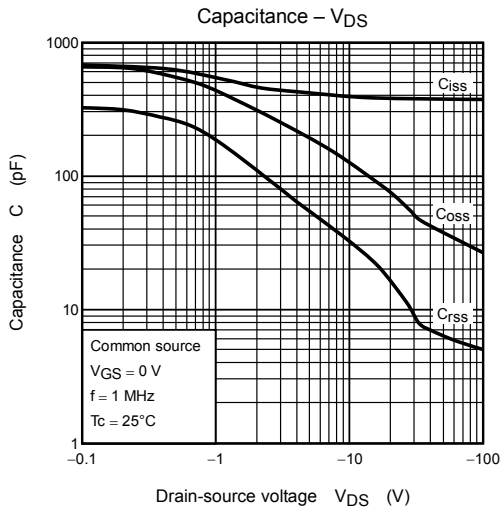
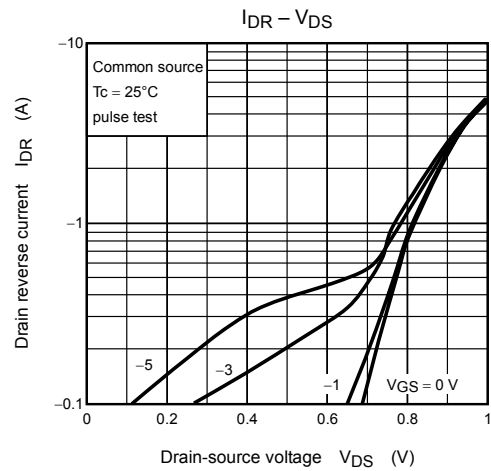
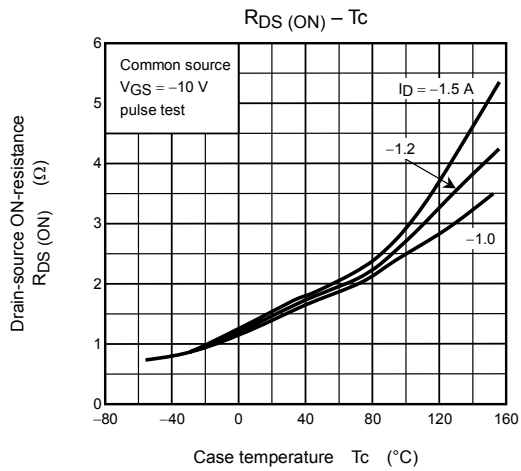
## Source-Drain Ratings and Characteristics (Ta = 25°C)

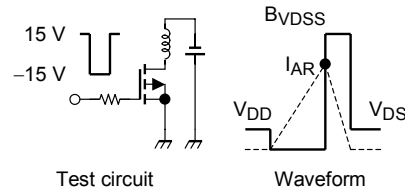
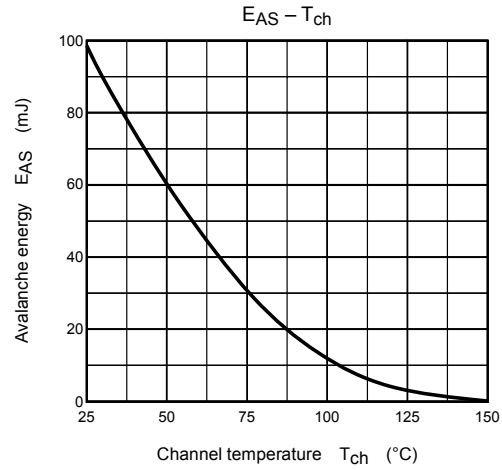
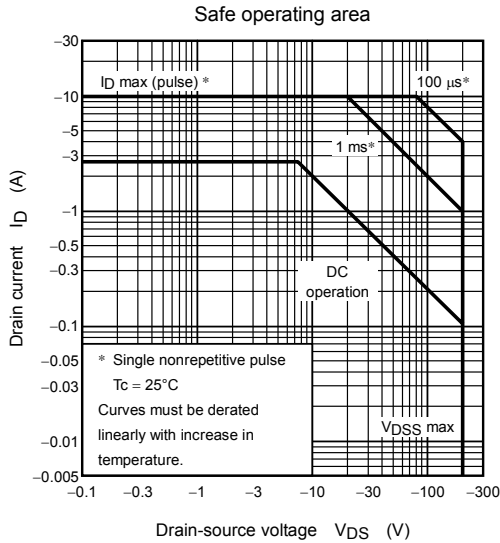
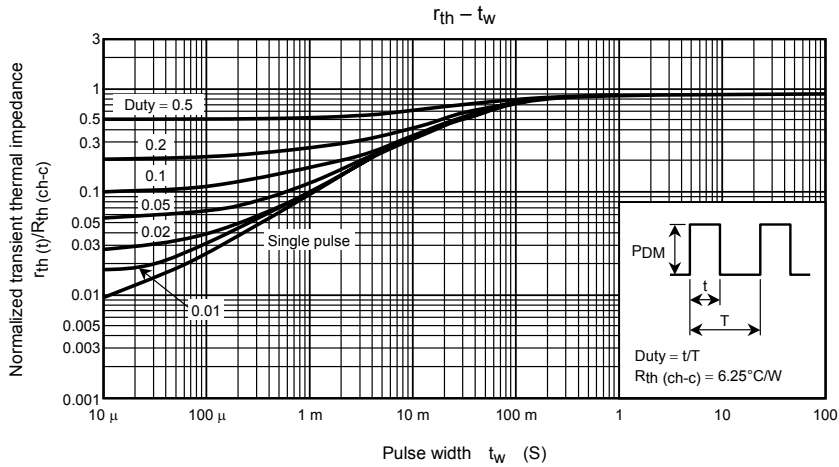
Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Continuous drain reverse current (Note 1)	$I_{DR}$	—	—	—	-2.5	A
Pulse drain reverse current (Note 1)	$I_{DRP}$	—	—	—	-10	A
Forward voltage (diode)	$V_{DSF}$	$I_{DR} = -2.5\text{ A}, V_{GS} = 0\text{ V}$	—	—	2.0	V
Reverse recovery time	$t_{rr}$	$I_{DR} = -2.5\text{ A}, V_{GS} = 0\text{ V}, dI_{DR}/dt = 100\text{ A}/\mu\text{s}$	—	135	—	ns
Reverse recovery charge	$Q_{rr}$		—	0.81	—	$\mu\text{C}$

## Marking









$R_G = 25 \Omega$   
 $V_{DD} = -50 \text{ V}, L = 25.2 \text{ mH}$

$$E_{AS} = \frac{1}{2} \cdot L \cdot I^2 \cdot \left( \frac{B_{V_{DS}}}{B_{V_{DS}} - V_{DD}} \right)$$

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